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# 2008 Solar Annual Review Meeting

**Session: CIGS**

**Company or Organization: SoloPower, Inc.**

**Funding Opportunity: PV Incubator**

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# Budget and Solar America Initiative Alignment



<b><i>Company or Organization</i></b>			
<b>Project Beginning Date</b>	<b>FY07 Budget</b>	<b>FY08 Budget</b>	<b>Total Budget</b>
9/28/2007	-	\$ 1.07millions	\$ 2.37millions*

- This project supports the Solar America Initiative by:
  - Development of a low cost CIGS thin film PV technology based on electrodeposition
  - Establishment of a 10-20 MW/yr capacity pilot plant operation by the end of the project period as a transitional step to full-scale manufacturing of 100 MW or more by 2010
  - Therefore, driving towards the overall goal of grid parity by 2015

\* NREL subcontract portion including FY09 amount

# Project Overview



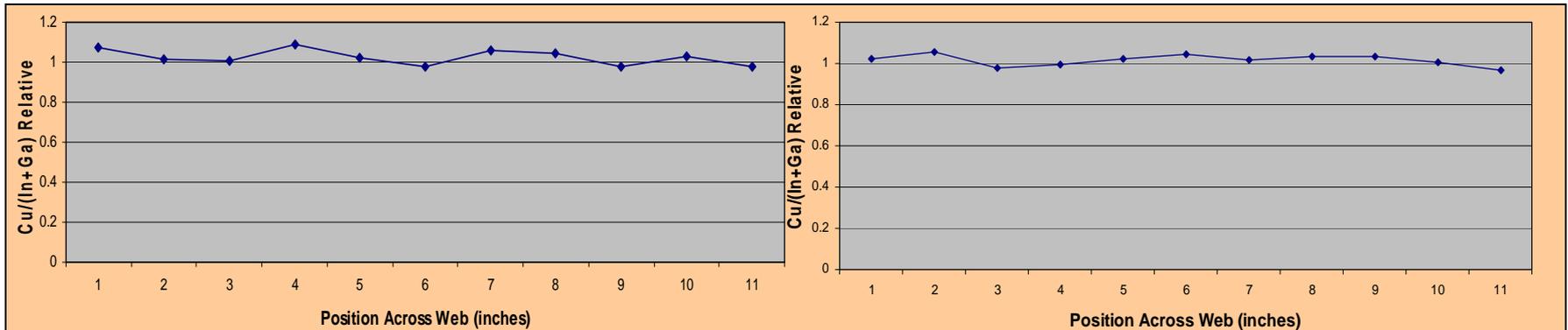
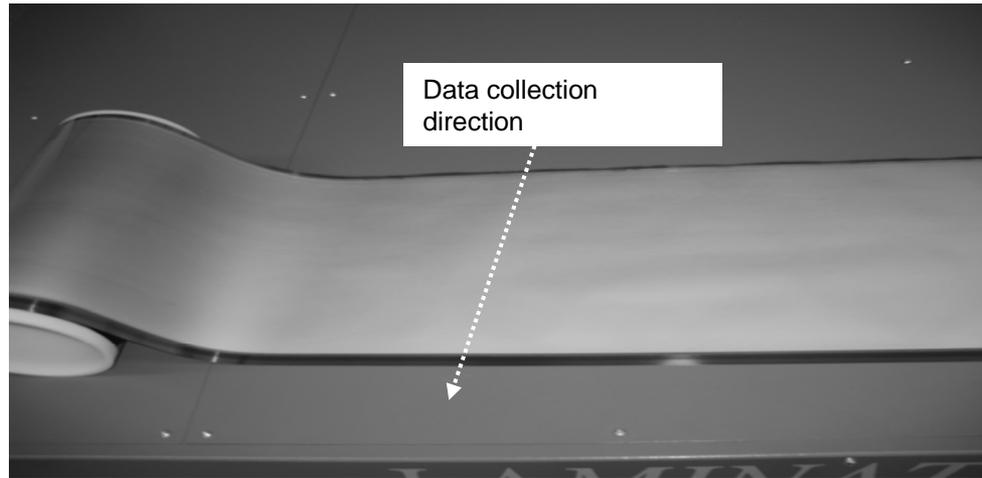
- SoloPower developed a low cost CIGS technology based on roll-to-roll electrodeposition technique
  - Electroplating hardware is low cost
  - Process is high throughput
  - Starting chemicals are low cost (no need for pre-formed materials)
  - Materials utilization is near 100%
  - Method is easily scalable
  - Compositional control is good
- Good large area cell efficiencies and modules have been demonstrated within 2 years of company start-up



# Project Overview, cont'



- Compositional control in electroplating is good



At 2ft

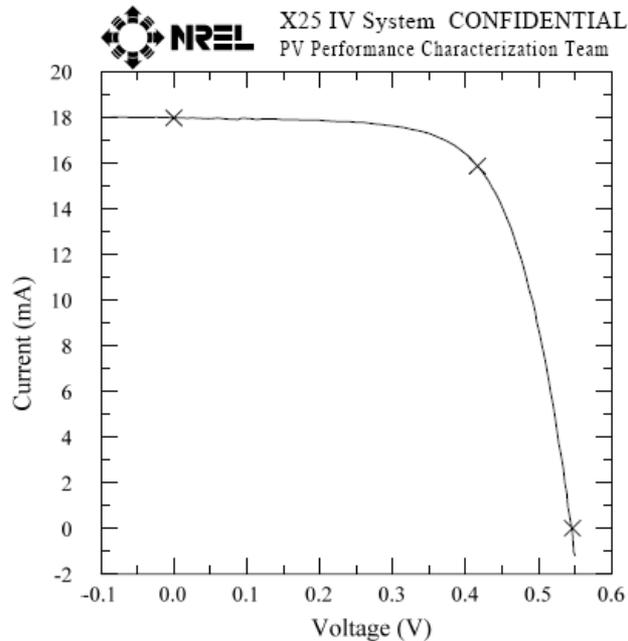
At 32ft

# Project Overview, cont'



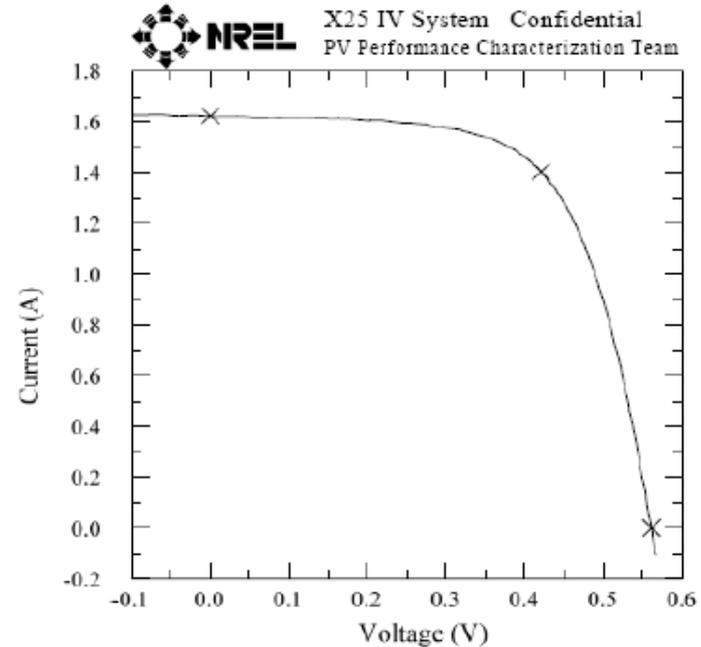
- Good cell efficiencies have been demonstrated

Spectrum: AM1.5-G (IEC 60904)      Device Temperature:  $25.0 \pm 1.0$  °C  
Device Area:  $0.480 \text{ cm}^2$       Irradiance:  $1000.0 \text{ W/m}^2$



$V_{oc} = 0.5463 \text{ V}$        $I_{max} = 15.876 \text{ mA}$   
 $I_{sc} = 17.987 \text{ mA}$        $V_{max} = 0.4161 \text{ V}$   
 $J_{sc} = 37.473 \text{ mA/cm}^2$        $P_{max} = 6.6063 \text{ mW}$   
Fill Factor = 67.23 %      Efficiency =  $13.76 \%$

Spectrum: AM1.5-G (IEC 60904)      Device Area:  $51.868 \text{ cm}^2$   
Irradiance:  $1000.0 \text{ W/m}^2$



$V_{oc} = 0.5613 \text{ V}$        $I_{max} = 1.4030 \text{ A}$   
 $I_{sc} = 1.6230 \text{ A}$        $V_{max} = 0.4210 \text{ V}$   
 $J_{sc} = 31.291 \text{ mA/cm}^2$        $P_{max} = 0.5908 \text{ W}$   
Fill Factor = 64.85 %      Efficiency =  $11.39 \%$

# Project Overview, cont'



- From cells to modules

- SoloPower made its first “proof of concept” solar cell in January 2006, using films plated in a beaker. This 0.5 cm<sup>2</sup> cell measured at IEC (U. Delaware) yielded about 7% efficiency
- SoloPower started module fabrication in late 2007/early 2008 period
- A module delivered to NREL measured to be 7.71% efficient
- Packaging materials and process of record have been developed and passed over 1500 hrs of 85C/85%RH test with no device degradation.



# Project Alignment with Technology Roadmap



Need	Significance	SoloPower Approach
<b>(1) Enhance Module Efficiency and Lower Module Cost</b>		
<i>(a) Comparative evaluation of production vs. high performance CIGS devices.</i>	<i>Increasing module efficiency from 10-15% can reduce module cost to &lt;\$1/W with no change in production cost.</i>	<ul style="list-style-type: none"> <li>◦ Identify factors contributing to efficiency variation between small (0.47 cm<sup>2</sup>) and large (100 cm<sup>2</sup>) devices.</li> <li>◦ Batch vs. R-t-R process.</li> </ul>
<i>(c) Improve schemes outside the CIGS layer.</i>	<i>Understanding necessary materials, devices, and processing changes to improve efficiency, yield and reliability.</i>	<ul style="list-style-type: none"> <li>◦ Develop/identify interconnect materials and processes compatible with CIGS devices.</li> </ul>
<i>(d) Higher throughput from higher rates and/or lower thickness.</i>	<i>Increase rates to the 30 um/h or greater required in vacuum processing for low equipment-depreciation rates.</i>	<ul style="list-style-type: none"> <li>◦ Work with 1 um thick absorber.</li> <li>◦ Work on increasing throughput further.</li> </ul>
<i>(e) Develop alternative fabrication processes</i>	<i>Reduce manufacturing cost by using lower-cost and higher-performance processing.</i>	<ul style="list-style-type: none"> <li>◦ Using electrodeposition.</li> </ul>
<b>(2) Science/Engineering Base: Discover New/Alternative Approaches</b>		
<i>(a) Characterize and model CIGS materials/device physics, determine pathways and kinetics for CIGS materials and cell growth.</i>	<i>Understand the factors limiting cell and module performance; improved engineering basis for manufacturing processes.</i>	<ul style="list-style-type: none"> <li>◦ Study reaction kinetics during crystallization of CIGS absorber to improve absorber quality.</li> </ul>
<i>(b) Develop improved in situ diagnostic tools</i>	<i>Improved process monitoring and control</i>	<ul style="list-style-type: none"> <li>◦ Determine best in-situ techniques and embed them into R-t-R tools.</li> </ul>

# Project Update



	Planned work since last Program Review		Status	Deliverable
Past	Optimize metal foil substrate, demonstrate 50cm <sup>2</sup> , >7% cells		Completed on time	D2
	Absorber development (>8% cells)		Completed on time	D1, D4
	Large area cell fabrication (100 cm <sup>2</sup> cells, 10%)		Completed on time	D5
	Roll-to-roll processing (composition control)		Completed on time	D3, D6
	Module fabrication (0.5 m <sup>2</sup> module, 7%)		Completed on time	D7
	Building manufacturing line (move into facility and order tools)		Completed on time	
	100 cm <sup>2</sup> cells (R-t-R processing)			D8
11% efficient 100 cm <sup>2</sup> cells			D9	
Module fabrication (1 m <sup>2</sup> , 8%)			D10	

# Obstacle Discussion



- No fundamental obstacles or barriers have been identified that would cause problems for reaching the remaining milestones and delivery of the last three deliverables to successfully complete this Phase I program

# Acknowledgement



- We acknowledge the critical support and quick response of the Measurement and Characterization Group at NREL in the areas of material characterization, electron microscopy, and surface analysis; and the Thin Film Group for bench-marking SoloPower thin films and devices